NSN 5961-00-122-5563

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-122-5563 **Inclosure Material:** Metal **Overall Height:** Between 0.330 inches and 0.505 inches **End Application:** Virginia class cg (41), ticonderoga class cg(47), emory s.Land class as, spruance class dd(963), tarawa class lha, nimitz class cvn, avenger class mcm, kidd class ddg, oliver perry class ffg **Mounting Facility Quantity:** 1 **Internal Configuration:** Field effect **Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.544 inches and 0.562 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 repetitive peak off-state voltage **Special Features:** Weapons system essential; junction pattern arrangement: np **Terminal Type And Quantity:** 1 threaded stud and 2 tab, solder lug **Specification Data:** 80313-release 6188 professional/industrial association standard Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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